# imall

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### Features

- Serial Peripheral Interface (SPI) Compatible
- Supports SPI Modes 0 (0,0) and 3 (1,1) Data Sheet Describes Mode 0 Operation
- Low-voltage and Standard-voltage Operation
  - $-2.7 (V_{CC} = 2.7V \text{ to } 5.5V)$
- 1.8 (V<sub>CC</sub> = 1.8V to 5.5V)
- 20 MHz Clock Rate (5V)
- 8-byte Page Mode
- **Block Write Protection**
- Protect 1/4, 1/2, or Entire Array
- Write Protect (WP) Pin and Write Disable Instructions for Both Hardware and Software **Data Protection**
- Self-timed Write Cycle (5 ms max)
- High Reliability
  - Endurance: One Million Write Cycles
  - Data Retention: 100 Years
- Automotive Grade, Extended Temperature and Lead-free/Halogen-free Devices Available
- 8-lead PDIP, 8-lead JEDEC SOIC, 8-lead MAP and 8-lead TSSOP Packages

### Description

The AT25010A/020A/040A provides 1024/2048/4096 bits of serial electrically erasable programmable read-only memory (EEPROM) organized as 128/256/512 words of 8 bits each. The device is optimized for use in many industrial and commercial applications where low-power and low-voltage operation are essential. The AT25010A/020A/040A is available in space saving 8-lead PDIP, 8-lead JEDEC SOIC, 8-lead MAP, and 8-lead TSSOP packages.

The AT25010A/020A/040A is enabled through the Chip Select pin ( $\overline{CS}$ ) and accessed via a three-wire interface consisting of Serial Data Input (SI), Serial Data Output (SO), and Serial Clock (SCK). All programming cycles are completely self-timed, and no separate erase cycle is required before write.

Block write protection is enabled by programming the status register with one of four blocks of write protection. Separate Program Enable and Program disable instructions are provided for additional data protection. Hardware data protection is provided via the WP pin to protect against inadvertent write attempts. The HOLD pin may be used to suspend any serial communication without resetting the serial sequence.

### Table 1. Pin Configuration

**Pin Name** 

CS

SCK

SI

SO

GND

VCC

WP

HOLD

Function	8-lead PDIP				8-lead SOIC		
Chip Select	<u>CS</u> □ 1	8			1	8 🗆 VC	с
Serial Data Clock	SO □ 2 ₩P □ 3	7	∃ HOLD ∃ SCK		2	7 - HO 6 - SC	
Serial Data Input	GND 🗆 4		∃ SI		4	5 🗆 SI	
Serial Data Output							
Ground	8-1	ead MAP	1		8-lea	ad TSSOP	
Power Supply			<del>cs</del> so		1		-
Write Protect	SCK 6	3	WP		3		
Suspends Serial Input	SI 5	4	GND	GND 🗔	4	5 🗔 SI	
Bottom view							



# SPI Serial **EEPROMs**

1K (128x8)

2K (256x8)

4K (512x8)

# AT25010A AT25020A AT25040A

3348H-SEEPR-9/04



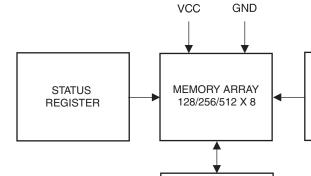


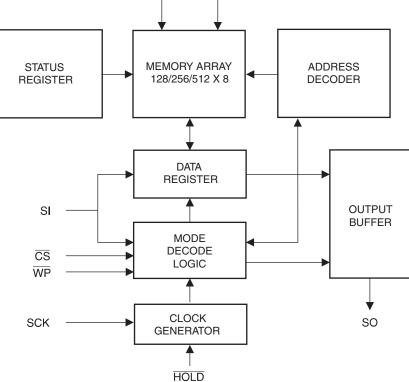
### **Absolute Maximum Ratings\***

Operating Temperature40°C to + 125°C
Storage Temperature65°C to + 150°C
Voltage on Any Pin with Respect to Ground1.0V to + 7.0V
Maximum Operating Voltage 6.25V
DC Output Current 5.0 mA

Figure 1. Block Diagram

\*NOTICE: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.





### Table 2. Pin Capacitance<sup>(1)</sup>

Applicable over recommended operating range from  $T_A = 25^{\circ}C$ , f = 1.0 MHz,  $V_{CC} = +5.0V$  (unless otherwise noted)

Symbol	mbol Test Conditions		Units	Conditions
C <sub>OUT</sub>	Output Capacitance (SO)	8	pF	$V_{OUT} = 0V$
C <sub>IN</sub>	Input Capacitance (CS, SCK, SI, WP, HOLD)	6	pF	$V_{IN} = 0V$

Note: 1. This parameter is characterized and is not 100% tested.

 Table 3. DC Characteristics<sup>(1)</sup>

Symbol	Parameter	Test Condition		Min	Тур	Max	Units
V <sub>CC1</sub>	Supply Voltage			1.8		5.5	V
V <sub>CC2</sub>	Supply Voltage			2.7		5.5	V
V <sub>CC3</sub>	Supply Voltage			4.5		5.5	V
I <sub>CC1</sub>	Supply Current	V <sub>CC</sub> = 5.0V at 20 MHz, S	O = Open, Read		8.5	10.0	mA
I <sub>CC2</sub>	Supply Current	V <sub>CC</sub> = 5.0V at 10 MHz, S	O = Open, Read, Write		4.5	5.0	mA
I <sub>CC3</sub>	Supply Current	V <sub>CC</sub> = 5.0V at 1 MHz, SC	) = Open, Read, Write		2.0	3.0	mA
I <sub>SB1</sub>	Standby Current	$V_{CC} = 1.8V, \overline{CS} = V_{CC}$			0.1	0.5	μA
I <sub>SB2</sub>	Standby Current	$V_{CC} = 2.7 V, \overline{CS} = V_{CC}$			0.2	1.0	μA
I <sub>SB3</sub>	Standby Current	$V_{CC} = 5.0V, \overline{CS} = V_{CC}$			2.0	3.5	μA
I	Input Leakage	$V_{IN} = 0V$ to $V_{CC}$	$V_{IN} = 0V$ to $V_{CC}$				μA
I <sub>OL</sub>	Output Leakage	$V_{IN} = 0V$ to $V_{CC}$ , $T_{AC} = 0^{\circ}0$	C to 70°C	-3.0		3.0	μA
$V_{IL}^{(1)}$	Input Low-voltage			-0.6		V <sub>CC</sub> x 0.3	V
V <sub>IH</sub> <sup>(1)</sup>	Input High-voltage					V <sub>CC</sub> + 0.5	V
V <sub>OL1</sub>	Output Low-voltage		I <sub>OL</sub> = 3.0 mA			0.4	V
V <sub>OH1</sub>	Output High-voltage	$3.6V \le V_{CC} \le 5.5V$	I <sub>OH</sub> = -1.6 mA	V <sub>CC</sub> -0.8			V
V <sub>OL2</sub>	Output Low-voltage		I <sub>OL</sub> = 0.15 mA			0.2	V
V <sub>OH2</sub>	Output High-voltage	$1.8V \le V_{CC} \le 3.6V$	I <sub>OH</sub> = −100 μA	V <sub>CC</sub> -0.2			V

Note: 1.  $V_{IL}$  min and  $V_{IH}$  max are reference only and are not tested.





#### Table 4. AC Characteristics

Applicable over recommended operating range from  $T_{AI} = -40$  to  $+85^{\circ}C$ ,  $V_{CC} = As$  Specified, CL = 1 TTL Gate and 30 pF (unless otherwise noted)

Symbol	Parameter	Voltage	Min	Мах	Units
f <sub>scк</sub>	SCK Clock Frequency	4.5 – 5.5 2.7 – 5.5 1.8 – 5.5	0 0 0	20 10 5	MHz
t <sub>RI</sub>	Input Rise Time	4.5 – 5.5 2.7 – 5.5 1.8 – 5.5		2 2 2	μs
t <sub>FI</sub>	Input Fall Time	4.5 – 5.5 2.7 – 5.5 1.8 – 5.5		2 2 2	μs
t <sub>wH</sub>	SCK High Time	4.5 – 5.5 2.7 – 5.5 1.8 – 5.5	20 40 80		ns
t <sub>WL</sub>	SCK Low Time	4.5 – 5.5 2.7 – 5.5 1.8 – 5.5	20 40 80		ns
t <sub>CS</sub>	CS High Time	4.5 – 5.5 2.7 – 5.5 1.8 – 5.5	100 100 200		ns
t <sub>CSS</sub>	CS Setup Time	4.5 – 5.5 2.7 – 5.5 1.8 – 5.5	100 100 200		ns
t <sub>CSH</sub>	CS Hold Time	4.5 – 5.5 2.7 – 5.5 1.8 – 5.5	100 100 200		ns
t <sub>SU</sub>	Data In Setup Time	4.5 - 5.5 2.7 - 5.5 1.8 - 5.5	20 40 80		ns
t <sub>H</sub>	Data In Hold Time	4.5 – 5.5 2.7 - 5.5 1.8 - 5.5	20 40 80		ns
t <sub>HD</sub>	Hold Setup Time	4.5 – 5.5 2.7 – 5.5 1.8 – 5.5	20 40 80		ns
t <sub>CD</sub>	Hold Hold Time	4.5 – 5.5 2.7 – 5.5 1.8 – 5.5	20 40 80		ns
t <sub>v</sub>	Output Valid	4.5 – 5.5 2.7 – 5.5 1.8 – 5.5	0 0 0	20 40 80	ns
t <sub>HO</sub>	Output Hold Time	4.5 – 5.5 2.7 – 5.5 1.8 – 5.5	0 0 0		ns

Table 4. AC Characteristics (Continued)

Applicable over recommended operating range from  $T_{AI} = -40$  to +85°C,  $V_{CC} = As$  Specified, CL = 1 TTL Gate and 30 pF (unless otherwise noted)

Symbol	Parameter	Voltage	Min	Max	Units
t <sub>LZ</sub>	Hold to Output Low Z	4.5 – 5.5 2.7 – 5.5 1.8 – 5.5	0 0 0	25 50 100	ns
t <sub>HZ</sub>	Hold to Output High Z	4.5 - 5.5 2.7 - 5.5 1.8 - 5.5		25 50 100	ns
t <sub>DIS</sub>	Output Disable Time	4.5 – 5.5 2.7 – 5.5 1.8 – 5.5		25 50 100	ns
t <sub>wc</sub>	Write Cycle Time	4.5 – 5.5 2.7 – 5.5 1.8 – 5.5		5 5 5	ms
Endurance <sup>(1)</sup>	5.0V, 25°C, Page Mode		1M		Write Cycles

Note: 1. This parameter is characterized and is not 100% tested.





### Serial Interface Description

MASTER: The device that generates the serial clock.

**SLAVE:** Because the serial clock pin (SCK) is always an input, the AT25010A/020A/040A always operates as a slave.

**TRANSMITTER/RECEIVER:** The AT25010A/020A/040A has separate pins designated for data transmission (SO) and reception (SI).

MSB: The Most Significant Bit (MSB) is the first bit transmitted and received.

**SERIAL OP-CODE:** After the device is selected with  $\overline{CS}$  going low, the first byte will be received. This byte contains the op-code that defines the operations to be performed. The op-code also contains address bit A8 in both the read and write instructions.

**INVALID OP-CODE:** If an invalid op-code is received, no data will be shifted into the AT25010A/020A/040A, and the serial output pin (SO) will remain in a high impedance state until the falling edge of  $\overline{CS}$  is detected again. This will reinitialize the serial communication.

**CHIP SELECT:** The AT25010A/020A/040A is selected when the  $\overline{CS}$  pin is low. When the device is not selected, data will not be accepted via the SI pin, and the SO pin will remain in a high impedance state.

**HOLD:** The HOLD pin is used in conjunction with the  $\overline{CS}$  pin to select the AT25010A/020A/040A. When the device is selected and a serial sequence is underway, HOLD can be used to pause the serial communication with the master device without resetting the serial sequence. To pause, the HOLD pin must be brought low while the SCK pin is low. To resume serial communication, the HOLD pin is brought high while the SCK pin is low (SCK may still toggle during HOLD). Inputs to the SI pin will be ignored while the SO pin is in the high impedance state.

**WRITE PROTECT:** The write protect pin ( $\overline{WP}$ ) will allow normal read/write operations when held high. When the  $\overline{WP}$  pin is brought low, all write operations are inhibited.

 $\overline{\text{WP}}$  going low while  $\overline{\text{CS}}$  is still low will interrupt a write to the AT25010A/020A/040A. If the internal write cycle has already been initiated,  $\overline{\text{WP}}$  going low will have no effect on any write operation.

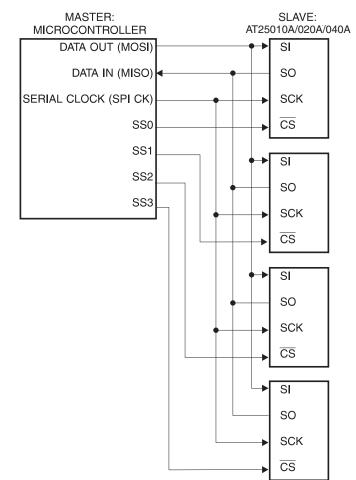


Figure 2. SPI Serial Interface



# AMEL

# Functional Description

The AT25010A/020A/040A is designed to interface directly with the synchronous serial peripheral interface (SPI) of the 6805 and 68HC11 series of microcontrollers.

The AT25010A/020A/040A utilizes an 8-bit instruction register. The list of instructions and their operation codes are contained in Figure 5. All instructions, addresses, and data are transferred with the MSB first and start with a high-to-low  $\overline{CS}$  transition.

Instruction Name	Instruction Format	Operation
WREN	0000 X110	Set Write Enable Latch
WRDI	0000 X100	Reset Write Enable Latch
RDSR	0000 X101	Read Status Register
WRSR	0000 X001	Write Status Register
READ	0000 A011	Read Data from Memory Array
WRITE	0000 A010	Write Data to Memory Array

Table 5. Instruction Set for the AT25010A/020A/040A

Note: "A" represents MSB address bit A8.

**WRITE ENABLE (WREN):** The device will power up in the write disable state when  $V_{CC}$  is applied. All programming instructions must therefore be preceded by a Write Enable instruction. The  $\overline{WP}$  pin must be held high during a WREN instruction.

**WRITE DISABLE (WRDI):** To protect the device against inadvertent writes, the Write Disable instruction disables all programming modes. The WRDI instruction is independent of the status of the  $\overline{WP}$  pin.

**READ STATUS REGISTER (RDSR):** The Read Status Register instruction provides access to the status register. The read/busy and write enable status of the device can be determined by the RDSR instruction. Similarly, the block write protection bits indicate the extent of protection employed. These bits are set by using the WRSR instruction.

Table 6. Status Register Format

	\$						
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
Х	Х	Х	Х	BP1	BP0	WEN	RDY

 Table 7. Read Status Register Bit Definition

Bit	Definition			
Bit 0 ( $\overline{\text{RDY}}$ ) Bit 0 = "0" ( $\overline{\text{RDY}}$ ) indicates the device is ready. Bit 0 = "1" indicates the write cycle is in progress.				
Bit 1 (WEN)Bit 1 = "0" indicates the device is not write enabled. Bit 1 = indicates the device is write enabled.				
Bit 2 (BP0)	See Table 8.			
Bit 3 (BP1)	See Table 8.			
Bits 4–7 are "0"s when device is not in an internal write cycle.				
Bits 0–7 are "1"s during an i	nternal write cycle.			

WRITE STATUS REGISTER (WRSR): The WRSR instruction allows the user to select one of four levels of protection. The AT25010A/020A/040A is divided into four array segments. One-quarter, one-half, or all of the memory segments can be protected. Any of the data within any selected segment will therefore be read only. The block write protection levels and corresponding status register control bits are shown in Table 8.

Bits BP1 and BP0 are nonvolatile cells that have the same properties and functions as the regular memory cells (e.g., WREN,  $t_{WC}$ , RDSR).

	Status Register Bits		Array Addresses Protected			
Level	BP1	BP0	AT25010A	AT25020A	AT25040A	
0	0	0	None	None	None	
1 (1/4)	0	1	60–7F	C0–FF	180–1FF	
2 (1/2)	1	0	40–7F	80–FF	100–1FF	
3 (All)	1	1	00–7F	00-FF	000–1FF	

Table 8. Block Write Protect Bits

**READ SEQUENCE (READ):** Reading the AT25010A/020A/040A via the SO pin requires the following sequence. After the  $\overline{CS}$  line is pulled low to select a device, the read op-code (including A8) is transmitted via the SI line followed by the byte address to be read (A7–A0). Upon completion, any data on the SI line will be ignored. The data (D7–D0) at the specified address is then shifted out onto the SO line. If only one byte is to be read, the  $\overline{CS}$  line should be driven high after the data comes out. The read sequence can be continued since the byte address is automatically incremented and data will continue to be shifted out. When the highest address is reached, the address counter will roll over to the lowest address allowing the entire memory to be read in one continuous read cycle.

**WRITE SEQUENCE (WRITE):** In order to program the AT25010A/020A/040A, the Write Protect pin ( $\overline{WP}$ ) must be held high and two separate instructions must be executed. First, the device *must be write enabled* via the WREN instruction. Then a Write (WRITE) instruction may be executed. Also, the address of the memory location(s) to be programmed must be outside the protected address field location selected by the block write protection level. During an internal write cycle, all commands will be ignored except the RDSR instruction.

A Write instruction requires the following sequence. After the  $\overline{CS}$  line is pulled low to select the device, the WRITE op-code (including A8) is transmitted via the SI line followed by the byte address (A7–A0) and the data (D7–D0) to be programmed. Programming will start after the  $\overline{CS}$  pin is brought high. The low-to-high transition of the  $\overline{CS}$  pin must occur during the SCK low time immediately after clocking in the D0 (LSB) data bit.

The ready/busy status of the device can be determined by initiating a Read Status Register (RDSR) instruction. If Bit 0 = "1", the write cycle is still in progress. If Bit 0 = "0", the write cycle has ended. Only the RDSR instruction is enabled during the write programming cycle.

The AT25010A/020A/040A is capable of an 8-byte page write operation. After each byte of data is received, the three low-order address bits are internally incremented by one; the six high-order bits of the address will remain constant. If more than 8 bytes of data are transmitted, the address counter will roll over and the previously written data will be overwritten. The AT25010A/020A/040A is automatically returned to the write disable state at the completion of a write cycle.

**NOTE:** If the  $\overline{WP}$  pin is brought low or if the device is not write enabled (WREN), the device will ignore the Write instruction and will return to the standby state, when  $\overline{CS}$  is brought high. A new CS falling edge is required to reinitiate the serial communication.





### **Timing Diagrams**

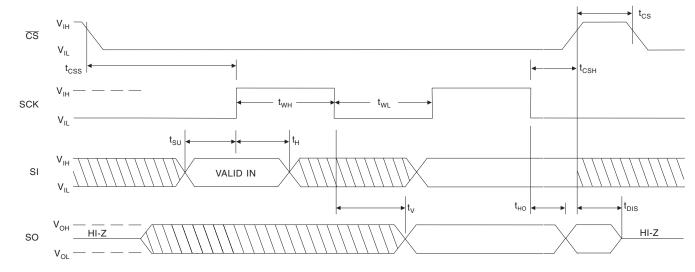
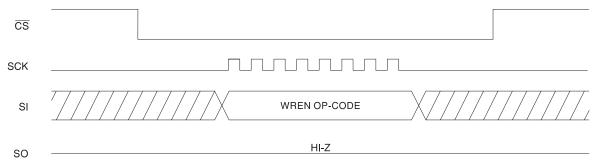
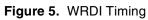
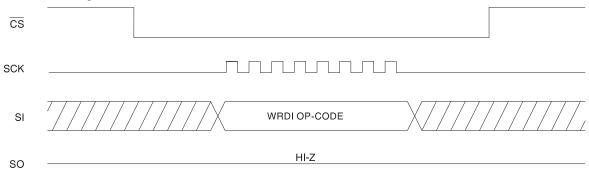


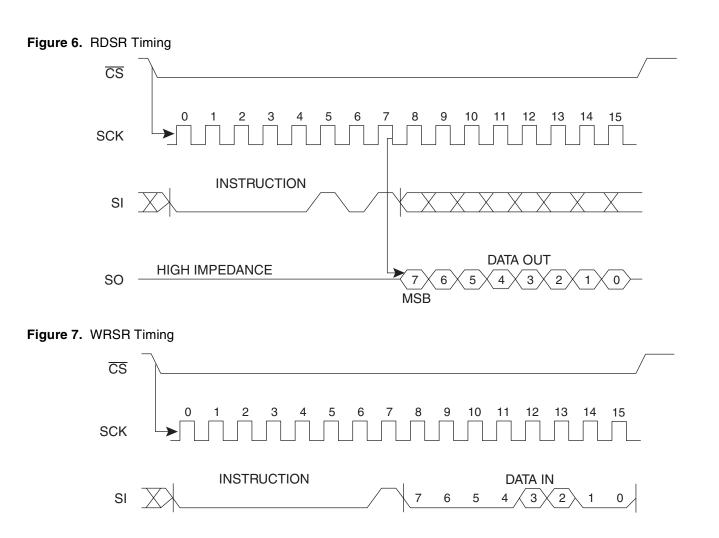
Figure 3. Synchronous Data Timing (for Mode 0)

### Figure 4. WREN Timing

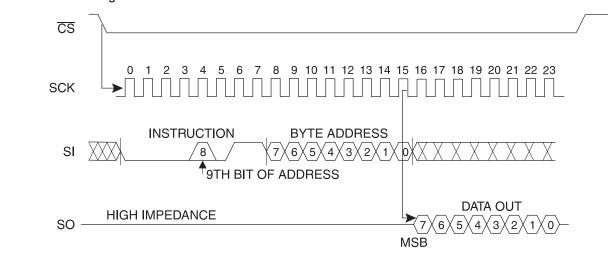








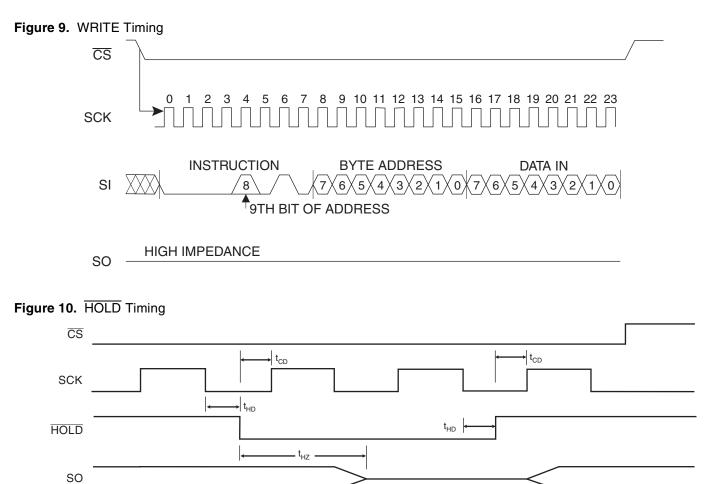








t<sub>LZ</sub>



### **AT25010A Ordering Information**

Ordering Code	Package	Operation Range
AT25010A-10PI-2.7	8P3	
AT25010AN-10SI-2.7	8S1	Industrial Temperature
AT25010A-10TI-2.7	8A2	(–40 to 85°C)
AT25010AY1-10YI-2.7	8Y1	
AT25010A-10PI-1.8	8P3	
AT25010AN-10SI-1.8	8S1	Industrial Temperature
AT25010A-10TI-1.8	8A2	(–40 to 85°C)
AT25010AY1-10YI-1.8	8Y1	
AT25010AN-10SU-2.7	8S1	
AT25010AN-10SU-1.8	8S1	
AT25010A-10TU-2.7	8A2	Lead-free/Halogen-free/ Industrial Temperature
AT25010A-10TU-1.8	8A2	(–40 to 85°C)
AT25010AY1-10YU-2.7	8Y1	(-+0 10 85 C)
AT25010AY1-10YU-1.8	8Y1	

Note: For 2.7V devices used in the 4.5 to 5.5V range, please refer to performance values in Table 3 on page 3 and Table 4 on page 4.

Package Type		
8P3	8-lead, 0.300" Wide, Plastic Dual Inline Package (PDIP)	
8S1	8-lead, 0.150" Wide, Plastic Gull Wing Small Outline Package (JEDEC SOIC)	
8A2	8-lead, 0.170" Wide, Thin Shrink Small Outline Package (TSSOP)	
8Y1	8-lead, 4.90 mm x 3.00 mm Body, Dual Footprint, Non-leaded, Miniature Array Package (MAP)	
Options		
-2.7	Low Voltage (2.7 to 5.5V)	
-1.8	Low Voltage (1.8 to 5.5V)	





### **AT25020A Ordering Information**

Ordering Code	Package	Operation Range	
AT25020A-10PI-2.7	8P3		
AT25020AN-10SI-2.7	8S1	Industrial Temperature	
AT25020A-10TI-2.7	8A2	(−40 to 85°C)	
AT25020AY1-10YI-2.7	8Y1		
AT25020A-10PI-1.8	8P3		
AT25020AN-10SI-1.8	8S1	Industrial Temperature	
AT25020A-10TI-1.8	8A2	(−40 to 85°C)	
AT25020AY1-10YI-1.8	8Y1		
AT25020AN-10SU-2.7	8S1		
AT25020AN-10SU-1.8	8S1	Lood free/Lologen free/	
AT25020A-10TU-2.7	8A2	Lead-free/Halogen-free/ Industrial Temperature	
AT25020A-10TU-1.8	8A2	(–40 to 85°C)	
AT25020AY1-10YU-2.7	8Y1	(-40 10 65 C)	
AT25020AY1-10YU-1.8	8Y1		

Note: For 2.7V devices used in the 4.5 to 5.5V range, please refer to performance values in Table 3 on page 3 and Table 4 on page 4.

Package Type			
8P3	8-lead, 0.300" Wide, Plastic Dual Inline Package (PDIP)		
8S1	8-lead, 0.150" Wide, Plastic Gull Wing Small Outline Package (JEDEC SOIC)		
8A2	8-lead, 0.170" Wide, Thin Shrink Small Outline Package (TSSOP)		
8Y1	8-lead, 4.90 mm x 3.00 mm Body, Dual Footprint, Non-leaded, Miniature Array Package (MAP)		
Options			
-2.7	Low Voltage (2.7 to 5.5V)		
-1.8	Low Voltage (1.8 to 5.5V)		

# 14 AT25010A/020A/040A

### **AT25040A Ordering Information**

Ordering Code	Package	Operation Range	
AT25040A-10PI-2.7	8P3		
AT25040AN-10SI-2.7	8S1	Industrial Temperature	
AT25040A-10TI-2.7	8A2	(−40 to 85°C)	
AT25040AY1-10YI-2.7	8Y1		
AT25040A-10PI-1.8	8P3		
AT25040AN-10SI-1.8	8S1	Industrial Temperature	
AT25040A-10TI-1.8	8A2	(−40 to 85°C)	
AT25040AY1-10YI-1.8	8Y1		
AT25040AN-10SU-2.7	8S1		
AT25040AN-10SU-1.8	8S1		
AT25040A-10TU-2.7	8A2	Lead-free/Halogen-free/ Industrial Temperature	
AT25040A-10TU-1.8	8A2	(-40 to 85°C)	
AT25040AY1-10YU-2.7	25040AY1-10YU-2.7 8Y1		
AT25040AY1-10YU-1.8	8Y1		

Note: For 2.7V devices used in the 4.5 to 5.5V range, please refer to performance values in Table 3 on page 3 and Table 4 on page 4.

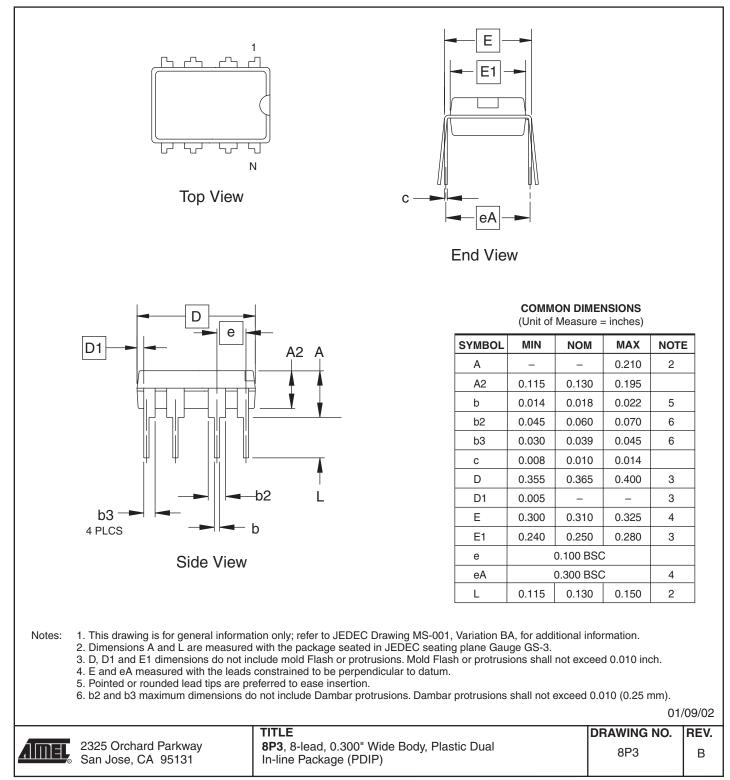
Package Type		
8P3	8-lead, 0.300" Wide, Plastic Dual Inline Package (PDIP)	
8S1	8-lead, 0.150" Wide, Plastic Gull Wing Small Outline Package (JEDEC SOIC)	
8A2	8-lead, 0.170" Wide, Thin Shrink Small Outline Package (TSSOP)	
8Y1	8-lead, 4.90 mm x 3.00 mm Body, Dual Footprint, Non-leaded, Miniature Array Package (MAP)	
Options		
-2.7	Low Voltage (2.7 to 5.5V)	
-1.8	Low Voltage (1.8 to 5.5V)	





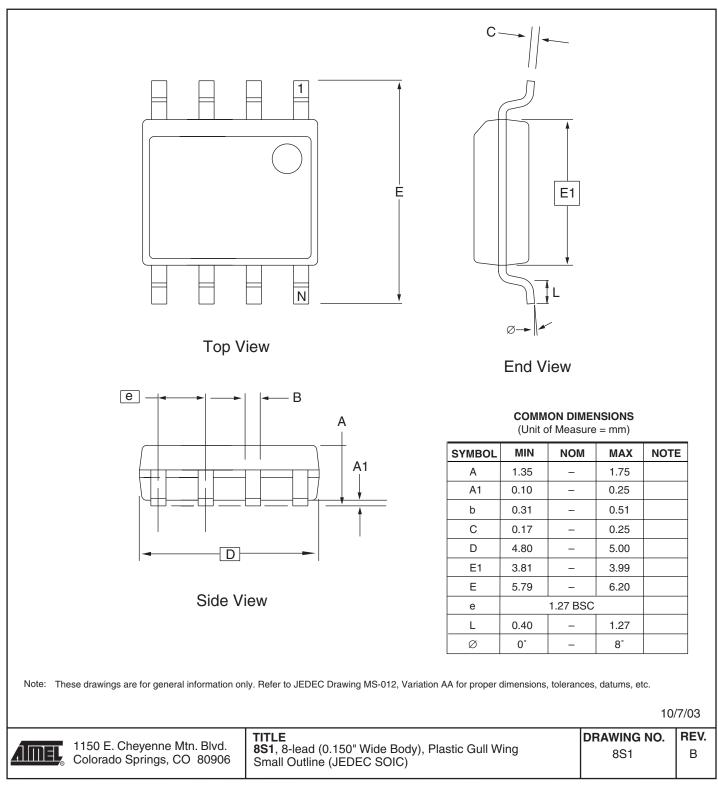
### **Packaging Information**





# 16 AT25010A/020A/040A

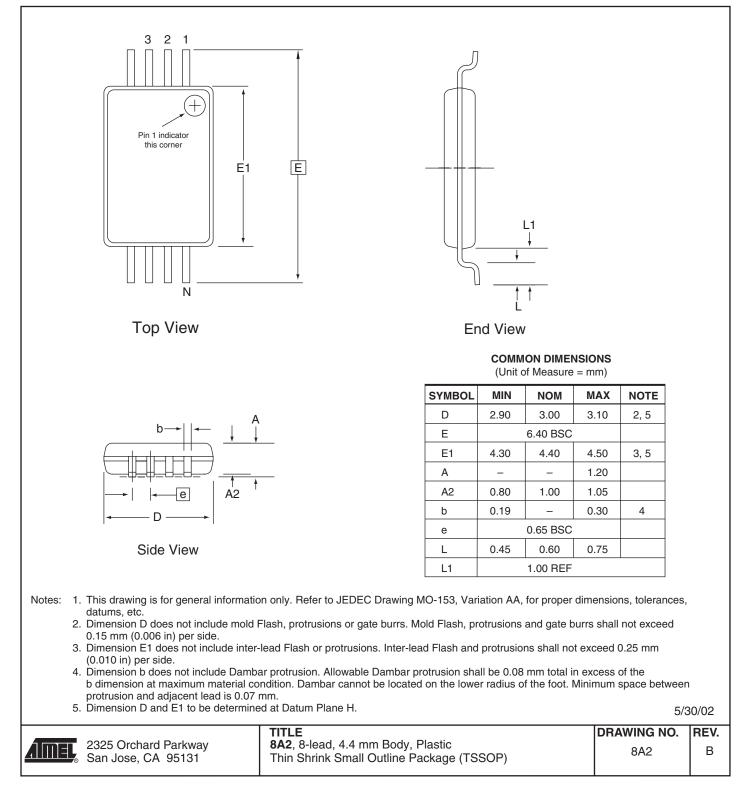
### 8S1 – JEDEC SOIC



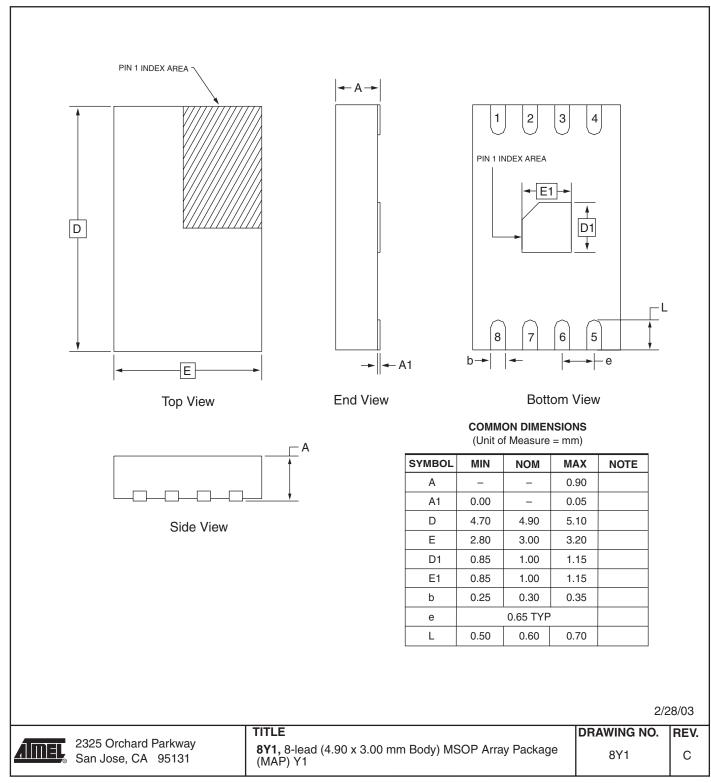




### 8A2 – TSSOP



### 8Y1 - MAP







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*Literature Requests* www.atmel.com/literature

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